

High Current Surface Mount PNP Silicon Switching Transistor for Load Management in Portable Applications

MMBT589LT1G, NSVMMBT589LT1G

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Symbol	Rating	Value	Unit
V_{CEO}	Collector – Emitter Voltage	-30	Vdc
V_{CBO}	Collector – Base Voltage	-50	Vdc
V_{EBO}	Emitter – Base Voltage	-5.0	Vdc
I_C	Collector Current – Continuous	-1.0	Adc
I_{CM}	Collector Current – Peak	-2.0	A

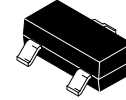
THERMAL CHARACTERISTICS

Symbol	Characteristic	Max	Unit
P_D	Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^\circ\text{C}$ Derate above 25°C	310 2.5	mW mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient (Note 1)	403	$^\circ\text{C}/\text{W}$
P_D	Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above 25°C	710 5.7	mW mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient (Note 2)	176	$^\circ\text{C}/\text{W}$
$P_{D\text{single}}$	Total Device Dissipation (Ref. Figure 8) (Single Pulse < 10 sec.)	575	mW
T_J, T_{stg}	Junction and Storage Temperature	-55 to +150	$^\circ\text{C}$

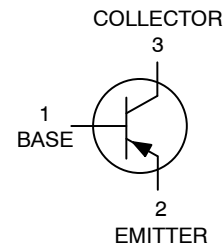
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 X 1.0 inch Pad

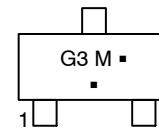
30 VOLTS, 2.0 AMPS PNP TRANSISTORS



SOT-23 (TO-236)
CASE 318
STYLE 6



MARKING DIAGRAM



G3 = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
MMBT589LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
NSVMMBT589LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Characteristic	Min	Max	Unit
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OFF CHARACTERISTICS

$V_{(BR)CEO}$	Collector – Emitter Breakdown Voltage ($I_C = -10\text{ mAdc}$, $I_B = 0$)	$\begin{array}{c} \\ -30 \end{array}$	–	Vdc
$V_{(BR)CBO}$	Collector – Base Breakdown Voltage ($I_C = -0.1\text{ mAdc}$, $I_E = 0$)	–50	–	Vdc
$V_{(BR)EBO}$	Emitter – Base Breakdown Voltage ($I_E = -0.1\text{ mAdc}$, $I_C = 0$)	–5.0	–	Vdc
I_{CBO}	Collector Cutoff Current ($V_{CB} = -30\text{ Vdc}$, $I_E = 0$)	–	–0.1	μAdc
I_{CES}	Collector–Emitter Cutoff Current ($V_{CES} = -30\text{ Vdc}$)	–	–0.1	μAdc
I_{EBO}	Emitter Cutoff Current ($V_{EB} = -4.0\text{ Vdc}$)	–	–0.1	μAdc

ON CHARACTERISTICS

h_{FE}	DC Current Gain (Note 3) (Figure 1) ($I_C = -1.0\text{ mA}$, $V_{CE} = -2.0\text{ V}$) ($I_C = -500\text{ mA}$, $V_{CE} = -2.0\text{ V}$) ($I_C = -1.0\text{ A}$, $V_{CE} = -2.0\text{ V}$) ($I_C = 2.0\text{ A}$, $V_{CE} = -2.0\text{ V}$)	$\begin{array}{c} 100 \\ 100 \\ 80 \\ 40 \end{array}$	$\begin{array}{c} - \\ 300 \\ - \\ - \end{array}$	–
$V_{CE(sat)}$	Collector – Emitter Saturation Voltage (Note 3) (Figure 3) ($I_C = -0.5\text{ A}$, $I_B = -0.05\text{ A}$) ($I_C = -1.0\text{ A}$, $I_B = 0.1\text{ A}$) ($I_C = -2.0\text{ A}$, $I_B = -0.2\text{ A}$)	$\begin{array}{c} - \\ - \\ - \end{array}$	$\begin{array}{c} -0.25 \\ -0.30 \\ -0.65 \end{array}$	V
$V_{BE(sat)}$	Base – Emitter Saturation Voltage (Note 3) (Figure 2) ($I_C = -1.0\text{ A}$, $I_B = -0.1\text{ A}$)	–	–1.2	V
$V_{BE(on)}$	Base – Emitter Turn-on Voltage (Note 3) ($I_C = -1.0\text{ A}$, $V_{CE} = -2.0\text{ V}$)	–	–1.1	V
f_T	Cutoff Frequency ($I_C = -100\text{ mA}$, $V_{CE} = -5.0\text{ V}$, $f = 100\text{ MHz}$)	100	–	MHz
Cobo	Output Capacitance ($f = 1.0\text{ MHz}$)	–	15	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle $\leq 2\%$



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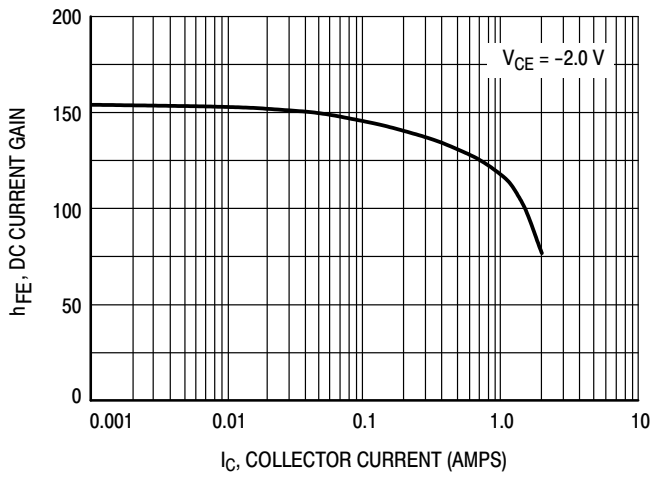


Figure 1. DC Current Gain versus Collector Current

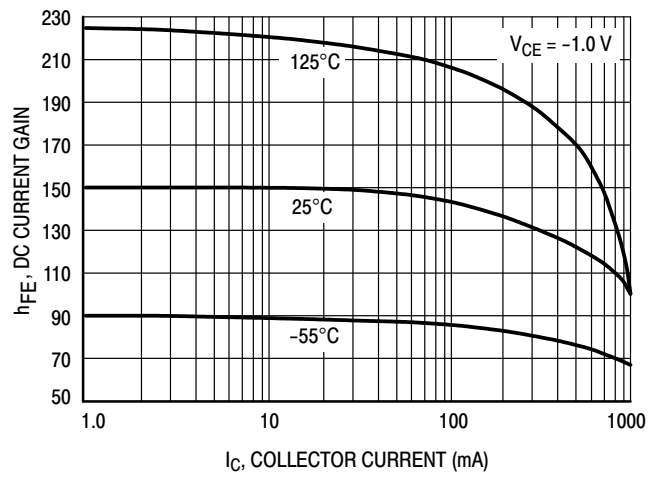


Figure 2. DC Current Gain versus Collector Current

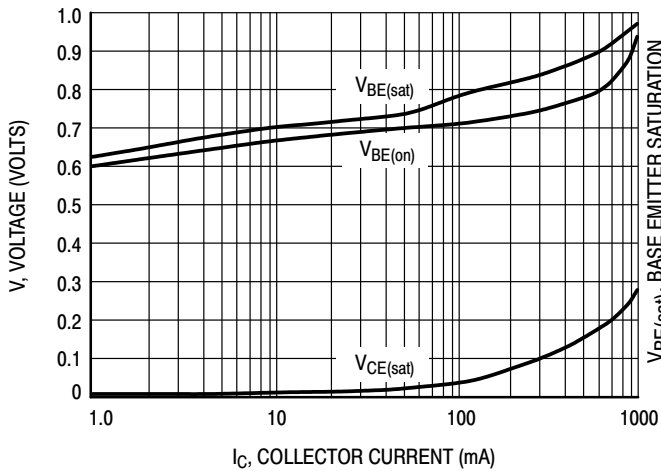


Figure 3. "On" Voltages

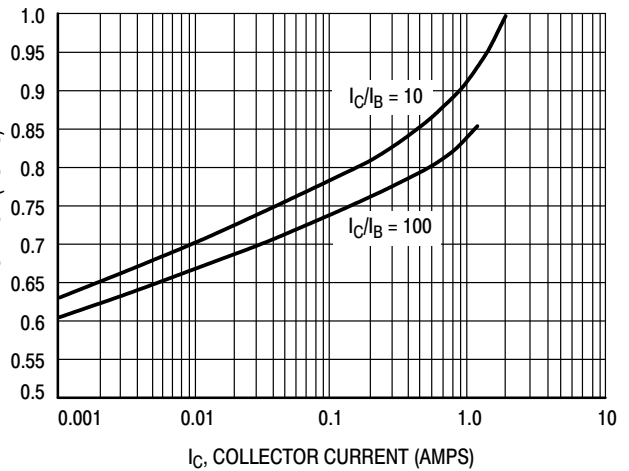


Figure 4. Base Emitter Saturation Voltage versus Collector Current

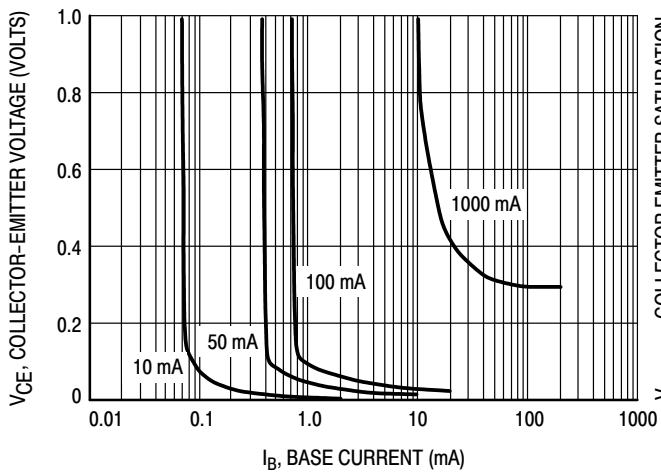


Figure 5. Collector Emitter Saturation Voltage versus Collector Current

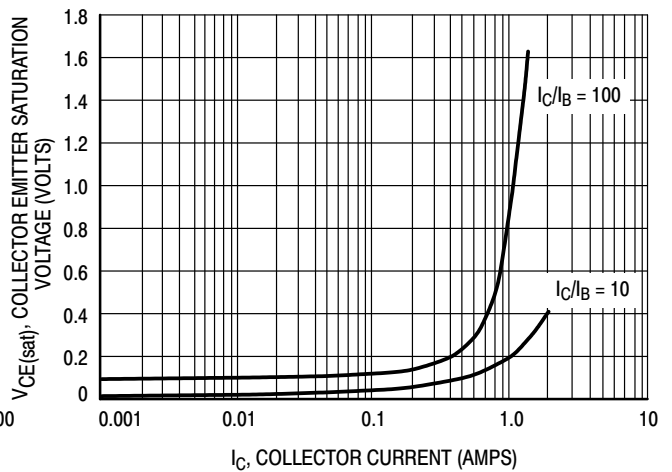


Figure 6. Collector Emitter Saturation Voltage versus Collector Current

MMBT589LT1G, NSVMMBT589LT1G

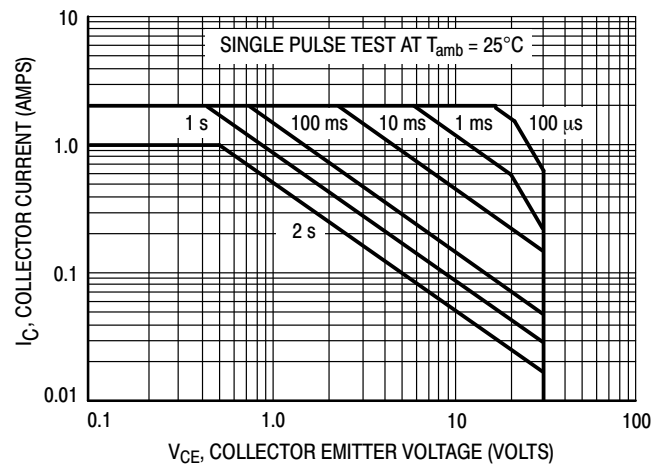


Figure 7. Safe Operating Area

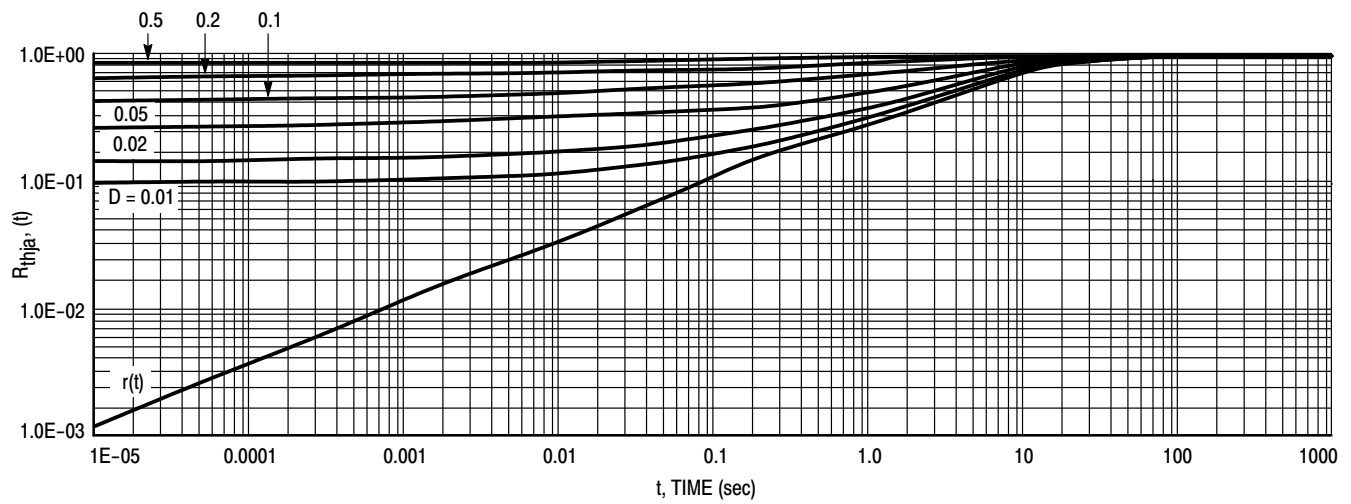


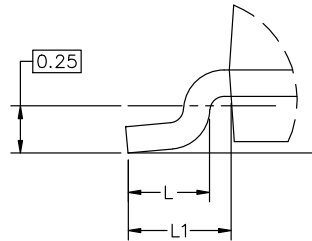
Figure 8. Normalized Thermal Response



SCALE 4:1

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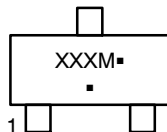


MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.89	1.00	1.11
A1	0.01	0.06	0.10
b	0.37	0.44	0.50
c	0.08	0.14	0.20
D	2.80	2.90	3.04
E	1.20	1.30	1.40
e	1.78	1.90	2.04
L	0.30	0.43	0.55
L1	0.35	0.54	0.69
HE	2.10	2.40	2.64
T	0°	---	10°

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERM/D.

STYLES ON PAGE 2

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STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 10: PIN 1. DRAIN 2. SOURCE 3. GATE	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13: PIN 1. SOURCE 2. DRAIN 3. GATE	STYLE 14: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 15: PIN 1. GATE 2. CATHODE 3. ANODE	STYLE 16: PIN 1. ANODE 2. CATHODE 3. CATHODE	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18: PIN 1. NO CONNECTION 2. CATHODE 3. ANODE	STYLE 19: PIN 1. CATHODE 2. ANODE 3. CATHODE-ANODE	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
STYLE 21: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 24: PIN 1. GATE 2. DRAIN 3. SOURCE	STYLE 25: PIN 1. ANODE 2. CATHODE 3. GATE	STYLE 26: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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